



US 2004/0141142A1

(19) **United States**(12) **Patent Application Publication** (10) **Pub. No.: US 2004/0141142 A1**
Choi et al. (43) **Pub. Date: Jul. 22, 2004**(54) **PANEL FOR A LIQUID CRYSTAL DISPLAY
AND METHOD OF FORMING THE SAME**(30) **Foreign Application Priority Data**

Nov. 14, 2002 (KR)..... 2002-70705

(76) Inventors: **Woo Choi**, Cheonan-city (KR);
Jun-Yeob Lee, Koyang-city (KR)**Publication Classification**Correspondence Address:
Frank Chau, Esq.
F. CHAU & ASSOCIATES, LLP
1900 Hempstead Turnpike
East Meadow, NY 11554 (US)(51) **Int. Cl.⁷** **G02F 1/1339**(52) **U.S. Cl.** **349/155**(57) **ABSTRACT**

A panel for a liquid crystal display including a substrate, and at least one spacer formed over the substrate. The at least one spacer has a tapered shape with an inclination angle in the range of about 20-about 70 degrees and a height in the range of about 2.5-about 5.0 microns.

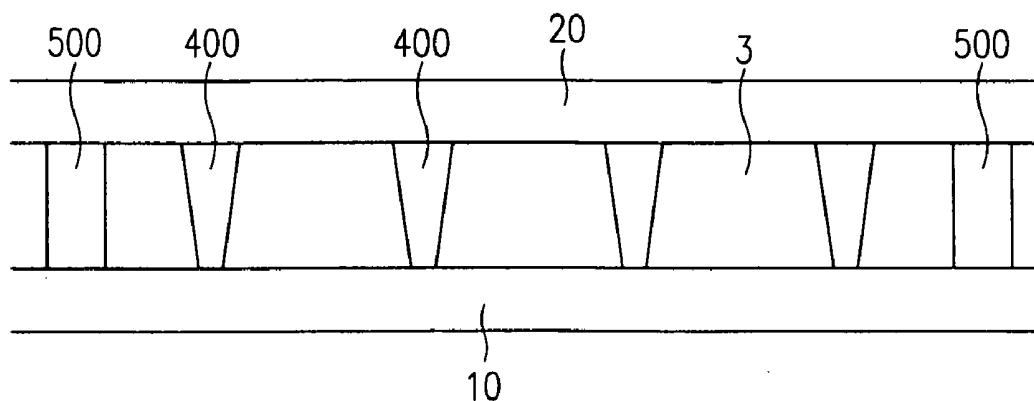
(21) Appl. No.: **10/714,495**(22) Filed: **Nov. 14, 2003**

FIG.1

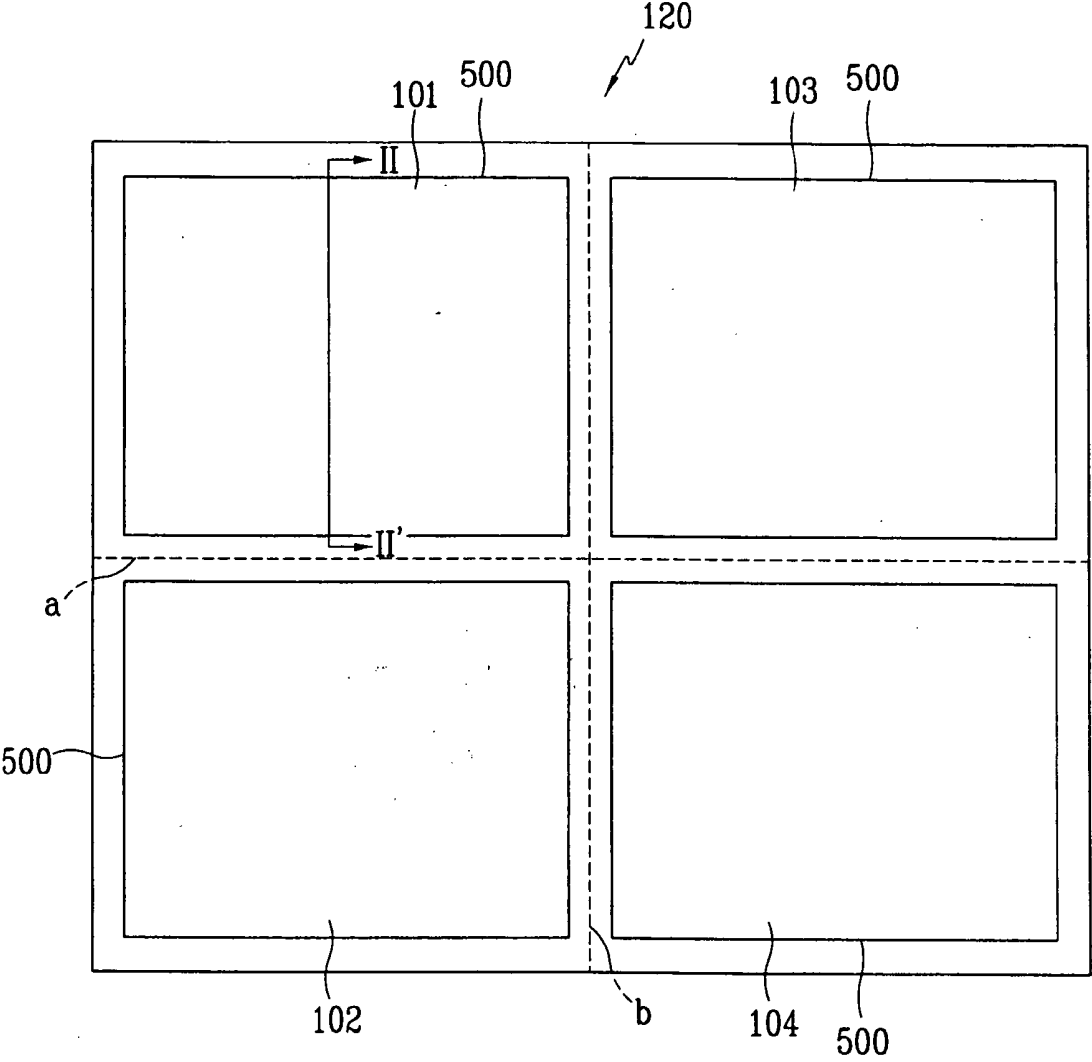


FIG.2

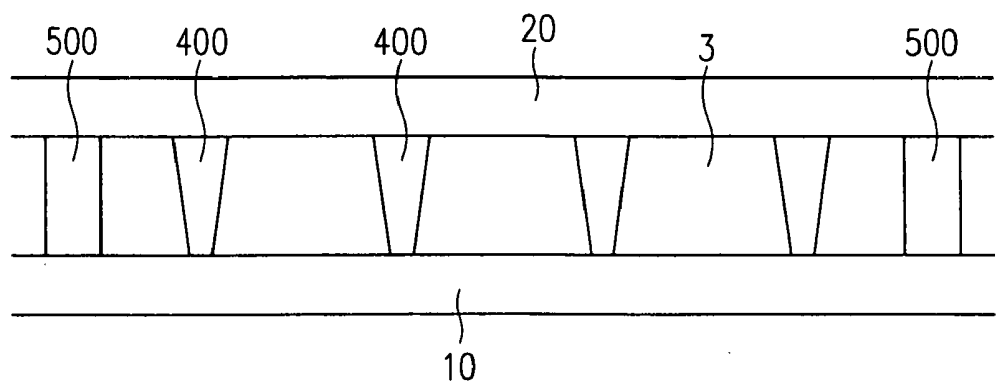


FIG.3

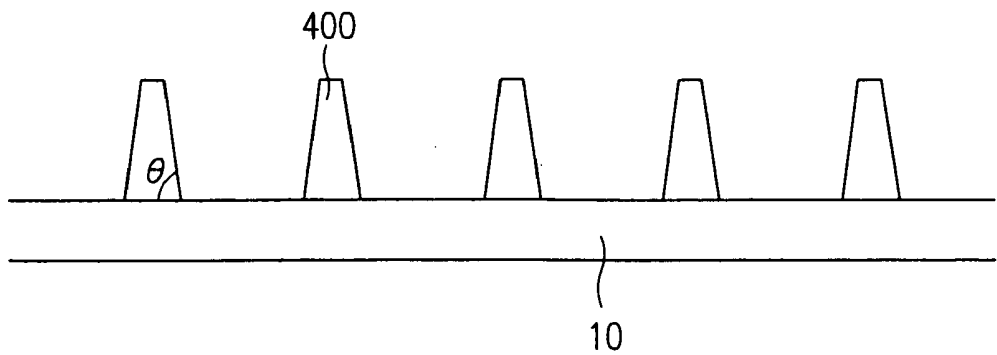


FIG. 4

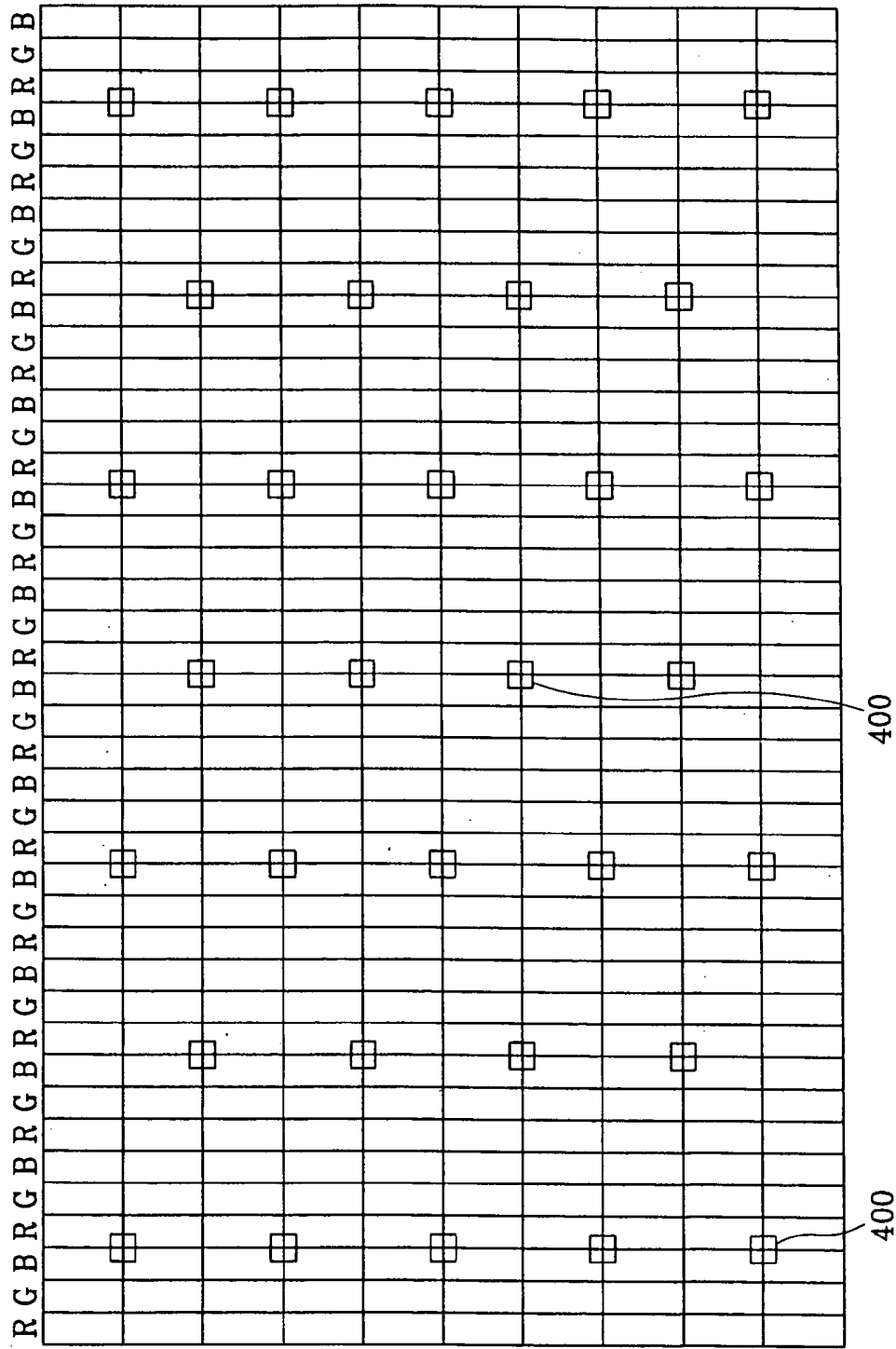


FIG. 5

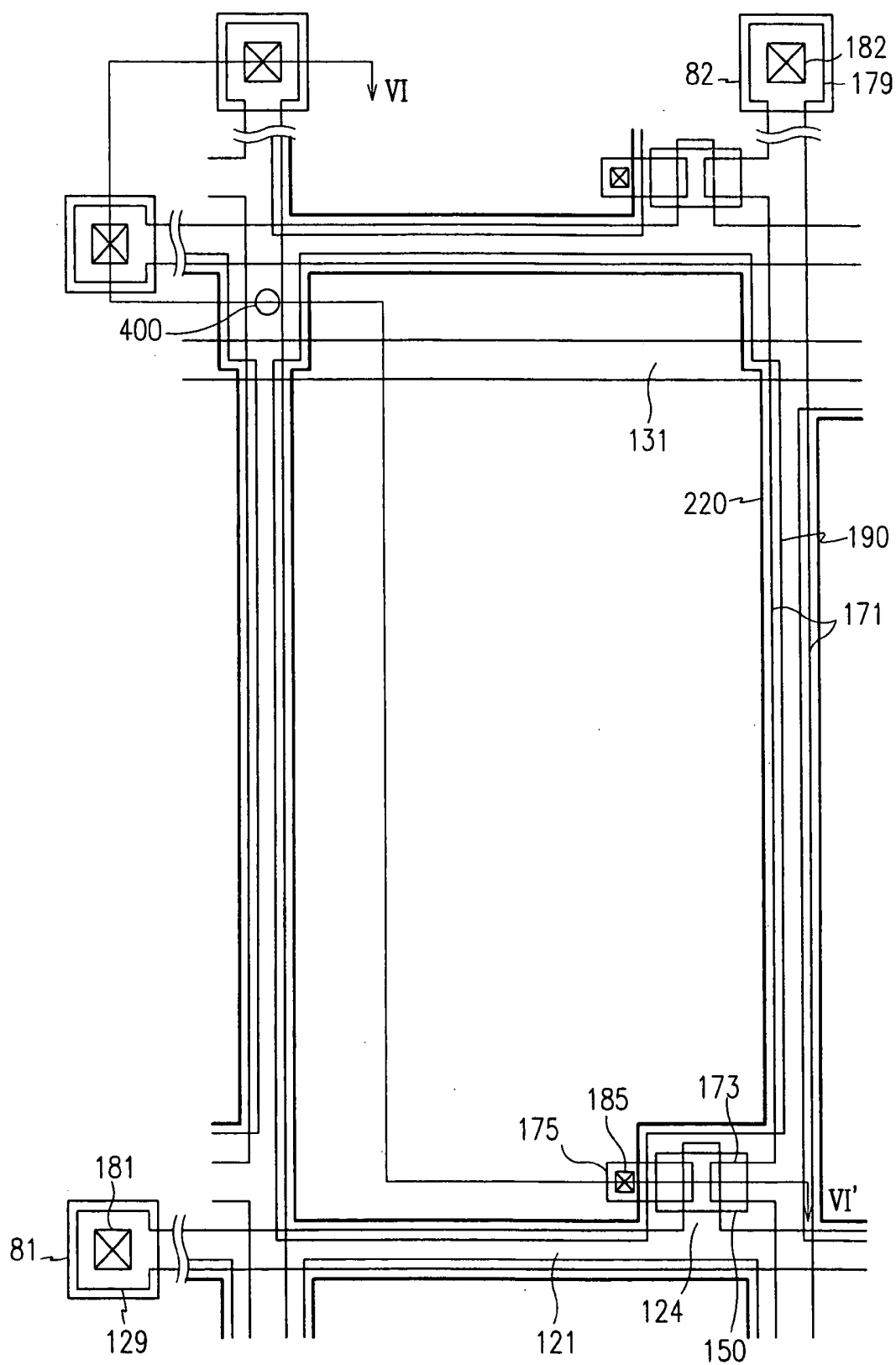
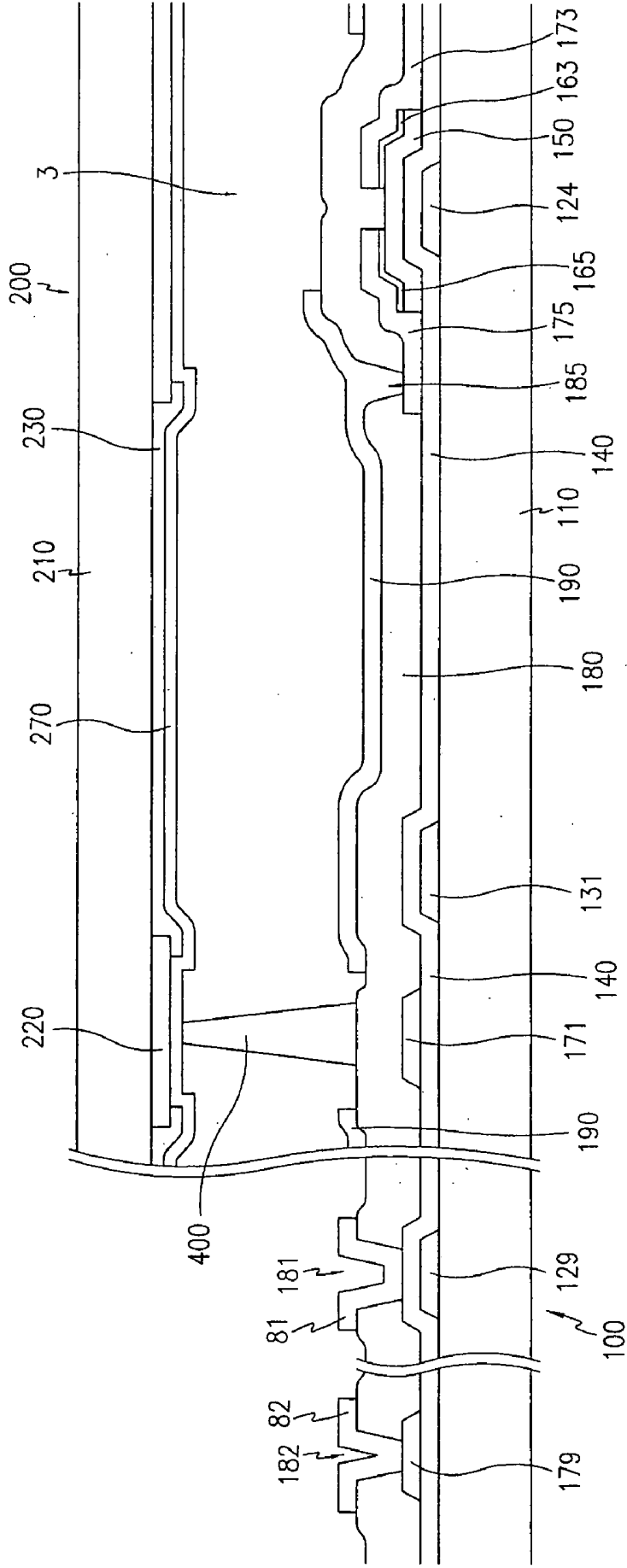


FIG. 6



PANEL FOR A LIQUID CRYSTAL DISPLAY AND METHOD OF FORMING THE SAME

BACKGROUND

[0001] (a) Technical Field

[0002] The present disclosure relates to a panel for a liquid crystal display, and in particular, to a liquid crystal display panel including spacers.

[0003] (b) Disclosure of Related Art

[0004] A conventional liquid crystal display (LCD) includes two panels in which at least one of the two panels is coated with an alignment layer and includes field-generating electrodes. A liquid crystal (LC) layer having dielectric anisotropy is filled in a gap (called a cell gap) between the panels. Electric fields are applied to the LC layer by the field-generating electrodes and the transmittance of light through the panels is controlled by adjusting the field strength, thereby displaying desired picture images.

[0005] The two panels are assembled by printing a sealant along a periphery of one of the panels and by hot-pressing the panels.

[0006] The cell gap is maintained by elastic spacers provided between the panels and spacers included in the sealant. The LC layer is encapsulated by the sealant. The spacers include spherical spacers spread on the panels and columnar spacers formed by photolithography.

[0007] The columnar spacers are vertically compressed to support the panels. When the cross sections of the spacers are too small, the spacers are apt to be deformed or to be damaged due to large compression deformation. If the cross sections of the spacers are too large, it is difficult to adjust the amount of the LC material to be filled in the gap between the panels due to the small compression deformation of the spacers. The inappropriate amount of the LC causes bubbles or non-uniform distribution of the LC.

[0008] As LCDs are made larger, it becomes important to keep the cell gap uniform to facilitate proper formation of the LC layer.

SUMMARY OF THE INVENTION

[0009] A panel for a liquid crystal display according to an embodiment of the invention includes a substrate, and at least one spacer formed over the substrate. The at least one spacer has a tapered shape with an inclination angle in the range of about 20-about 70 degrees and a height in the range of about 2.5-about 5.0 microns.

[0010] A liquid crystal display according to embodiment of the invention includes a first panel, a second panel disposed opposite the first panel, and a liquid crystal layer and at least one spacer disposed between the first panel and the second panel. The spacer has a tapered shape with an inclination angle in the range of about 20-about 70 degrees and a height in the range of about 2.5-about 5.0 microns.

[0011] A method of forming a liquid crystal display according to an embodiment of the invention includes forming a thin film transistor array panel including a plurality of pixel electrodes, and forming a plurality of spacers over the thin film transistor array panel between the plurality of pixel electrodes. A common electrode panel is formed and

a sealant is coated over at least one of the thin film transistor array panel and the common electrode panel. A liquid crystal layer is formed over the at least one of the thin film transistor array panel and the common electrode panel coated with the sealant. The thin film transistor array panel and the common electrode panel are adhered together to form a panel assembly, and the panel assembly is scribed to form a liquid crystal display.

[0012] In at least one embodiment of the invention, the spacers are located directly over the data lines.

BRIEF DESCRIPTION OF THE DRAWINGS

[0013] The present invention will become more apparent by describing preferred embodiments thereof in detail with reference to the accompanying drawings in which:

[0014] FIG. 1 is a plan view of a panel assembly for an LCD according to an embodiment of the present invention;

[0015] FIG. 2 is a sectional view of the panel assembly shown in FIG. 1 taken along the line II-II';

[0016] FIG. 3 is a sectional view of a panel and a plurality of column spacers formed thereon for the LCD shown in FIG. 2 before panel combination according to an embodiment of the present invention;

[0017] FIG. 4 shows locations of the first and the second spacers 400 shown in FIG. 2 according to an exemplary embodiment of the present invention;

[0018] FIG. 5 is a layout view of an LCD according to exemplary embodiments of the present invention;

[0019] FIG. 6 is a sectional view of the LCD shown in FIG. 5 taken along the line VI-VI' according to an exemplary embodiment of the invention; and

[0020] FIG. 7 is a sectional view of the LCD shown in FIG. 5 taken along the line VI-VI' according to another exemplary embodiment of the invention.

DETAILED DESCRIPTION OF PREFERRED EMBODIMENTS

[0021] The present invention now will be described more fully hereinafter with reference to the accompanying drawings, in which preferred embodiments of the invention are shown. The present invention may, however, be embodied in many different forms and should not be construed as limited to the embodiments set forth herein.

[0022] In the drawings, the thickness of layers, films and regions are exaggerated for clarity. Like numerals refer to like elements throughout.

[0023] A panel assembly for LCDs according to an embodiment of the present invention will be now described in detail with reference to FIGS. 1 and 2.

[0024] FIG. 1 is a plan view of a panel assembly for LCDs according to an embodiment of the present invention and FIG. 2 is a sectional view of the panel assembly shown in FIG. 1 taken along the line II-II'.

[0025] As shown in FIGS. 1 and 2, a panel assembly 120 according to an embodiment of the present invention includes two panels 10 and 20 and a plurality of LC layers

3, a plurality of sealants **500**, and a plurality of columnar spacers **400**, which are disposed between the two panels **10** and **20**.

[0026] The panel assembly **120** includes a plurality of, for example, four device areas divided by dotted lines A and B. The panel assembly **120** is separated into the respective LCDs by scribing the panel assembly **120** along the dotted lines A and B.

[0027] Each of the device areas (or an LCD) includes a display area **101**, **102**, **103** or **104** for displaying images. The display areas **101-104** are substantially enclosed by the sealant **500**, which also confines the LC layer **3**. The LC layer **3** may be formed after the panel assembly **120** is separated into the respective devices.

[0028] The spacers **400** are provided for maintaining a uniform gap between the panels **10** and **20** and the sealant **500** may contain spacers for supporting the panels **10** and **20** parallel to each other.

[0029] The spacers **400** have a compression deformation equal to or larger than about 0.40 microns in response to 5 gf and are compressed by about 0.2 microns. The concentration of the spacers **400** is preferably about 250-450/cm².

[0030] A method of manufacturing the spacers shown in FIG. 2 according to an embodiment of the present invention is described in detail with reference to FIGS. 3 and 4.

[0031] FIG. 3 is a sectional view of a panel and a plurality of column spacers formed thereon for an LCD before panel combination according to an embodiment of the present invention.

[0032] Referring to FIG. 3, a negative acrylic photoresist (not shown) is coated on an LC panel **10**. An exposure mask (not shown) including an opaque film having a plurality of transmissive areas, such as openings, is disposed on the panel **10**. The photoresist is then exposed to light through the exposure mask and developed to form a plurality of spacers **400** at desired positions.

[0033] Each contact area between the spacer **400** and the panel **10** may be circular or tetragonal and has a magnitude preferably in a range of about 600 to 1,000 square microns. For a circular contact area, the diameter of the circle is preferably equal to about 28-38 microns.

[0034] The height of the spacers **400** is about 2.5-5.0 microns. The spacers **400** preferably have a tapered shape with an inclination angle θ of about 20-70 degrees.

[0035] The spacers **400** have optimal compression deformation and disperse the stress exerted on the panels **10** and **20**. The spacers **400** maintain a uniform cell gap between the two panels **10** and **20** and facilitate proper adjustment of an amount of LC for forming the liquid crystal layer **3**.

[0036] One of the panels **10** and **20** shown in FIGS. 1 and 2 is a thin film transistor (TFT) array panel provided with a plurality of gate lines (not shown) and a plurality of data lines (not shown) for transmitting electrical signals such as scanning signals and data signals, a plurality of TFTs (not shown) electrically connected to the gate lines and the data lines for controlling the data signals, and a plurality of pixel electrodes (not shown) that receive the data voltages for driving the LC molecules.

[0037] The other of the panels **10** and **20** shown in FIGS. 1 and 2 is provided with a common electrode (not shown) facing the above-described pixel electrodes to generate electric fields for driving the LC molecules, and a plurality of color filters (not shown) for color display. The colors represented by the color filters preferably include three primary colors, i.e., red, green and blue.

[0038] In other embodiments of the invention, the color filters and/or the common electrode may be formed on the TFT array panel and the common electrode on the TFT array panel may have a shape of a bar or a stripe.

[0039] FIG. 4 shows locations of the spacers **400** shown in FIG. 2 according to an exemplary embodiment of the present invention.

[0040] Referring to FIG. 4, a plurality of red, green and blue color filters R, G and B are arranged in a stripe type. The spacers **400** are arranged in a regular or periodic manner along a row direction and a column direction. For example, the spacers **400** are located between the blue filters B and the red filters R and spaced apart from each other by predetermined transverse and longitudinal distances as shown in FIG. 4. In particular, the spacers **400** are preferably located over the gate lines, the data lines, or the TFTs.

[0041] An LC panel assembly according to an exemplary embodiment of the present invention will be described in more detail with reference to FIGS. 5-7.

[0042] FIG. 5 is a layout view of an LCD according to exemplary embodiments of the present invention, FIG. 6 is a sectional view of the LCD shown in FIG. 5 taken along the line VI-VI' according to one exemplary embodiment of the invention, and FIG. 7 is a sectional view of the LCD shown in FIG. 5 taken along the line VI-VI' according to another exemplary embodiment of the invention.

[0043] An LCD according to an embodiment of the present invention includes a TFT array panel **100**, a common electrode panel **200**, and a LC layer **3** and a plurality of column spacers **400** disposed between the panels **100** and **200**.

[0044] A plurality of gate lines **121** for transmitting gate signals and a plurality of storage electrode lines **131** are formed on an insulating substrate **110**.

[0045] The gate lines **121** and the storage electrode lines **131** extend substantially in a transverse direction and are separated from each other. A plurality of projections of each gate line **121** form a plurality of gate electrodes **124**. The storage electrode lines **131** are supplied with a predetermined voltage such as a common voltage, which is applied to a common electrode **270** on the common electrode panel **200** of the LCD.

[0046] The gate lines **121** and the storage electrode lines **131** may have a multi-layered structure including two films, a lower film (not shown) and an upper film (not shown), having different physical characteristics. The upper film is preferably made of low resistivity metal including an Al containing metal such as, for example, Al and Al alloy for reducing signal delay or voltage drop in the gate lines **121** and the storage electrode lines **131**. The lower film is preferably made of material such as, for example, Cr, Mo and Mo alloy, which has good contact characteristics with other materials such as indium tin oxide (ITO) or indium zinc oxide (IZO). An exemplary combination of the lower film material and the upper film material is Cr and Al—Nd alloy.

[0047] The lateral sides of the gate lines **121** and the storage electrode lines **131** are tapered, and the inclination angle of the lateral sides with respect to a surface of the substrate **110** is in a range of about 30-80 degrees.

[0048] A gate insulating layer **140** preferably made of silicon nitride (SiNx) is formed on the gate lines **121** and the storage electrode lines **131**.

[0049] A plurality of semiconductor islands **150** preferably made of hydrogenated amorphous silicon (abbreviated as "a-Si") or polysilicon are formed on the gate insulating layer **140**. The semiconductor islands **150** are located opposite the respective gate electrodes **124**.

[0050] A plurality of ohmic contact islands **163** and **165** preferably made of silicide or n+ hydrogenated a-Si heavily doped with n type impurity are formed on the semiconductor islands **150**.

[0051] The lateral sides of the semiconductor islands **150** and the ohmic contacts **163** and **165** are tapered, and the inclination angles thereof are preferably in a range of about 30-80 degrees.

[0052] A plurality of data lines **171** and a plurality of drain electrodes **175** separated from each other are formed on the ohmic contacts **163** and **165** and the gate insulating layer **140**.

[0053] The data lines **171** for transmitting data voltages extend substantially in the longitudinal direction and intersect the gate lines **121** and the storage electrode lines **131**. A plurality of branches of each data line **171**, which project toward the drain electrodes **175**, form a plurality of source electrodes **173**. A source electrode **173** and a drain electrode **175** in a pair are separated from each other and opposite each other with respect to a gate electrode **124**. A gate electrode **124**, a source electrode **173**, and a drain electrode **175** along with the semiconductor island **150** form a TFT having a channel between the source electrode **173** and the drain electrode **175**.

[0054] The data lines **171** and the drain electrodes **175** may also include a lower film (not shown) preferably made of Mo, Mo alloy or Cr and an upper film (not shown) located thereon and preferably made of Al containing metal.

[0055] Like the gate lines **121** and the storage electrode lines **131**, the data lines **171** and the drain electrodes **175** have tapered lateral sides, and the inclination angles thereof are in the range of about 30-80 degrees.

[0056] The ohmic contacts **163** and **165** are interposed only between the underlying semiconductor islands **150** and the overlying source electrodes **173** and the overlying drain electrodes **175** thereon and reduce the contact resistance therebetween.

[0057] A passivation layer **180** is formed on the data lines **171**, the drain electrodes **175**, and exposed portions of the semiconductor islands **150**, which are not covered with the data lines **171** and the drain electrodes **175**. The passivation layer **180** is preferably made of photosensitive organic material having a good flatness characteristic, low dielectric insulating material such as a-Si:C:O and a-Si:O:F formed by plasma enhanced chemical vapor deposition (PECVD), or inorganic material such as silicon nitride and silicon oxide. The passivation layer **180** may have a double-layered structure including a lower inorganic film and an upper organic film for preventing direct contact between the semiconductor islands **150** and an organic film.

[0058] The passivation layer **180** has a plurality of contact holes **182** and **185** exposing end portions **179** of the data lines **171** and the drain electrodes **175**, respectively. The passivation layer **180** also has a plurality of contact holes **181** exposing end portions **129** of the gate lines **121**. The contact holes **181**, **182** and **185** can have various shapes such as, for example, a polygonal or circular shape. The area of each contact hole **181**, **182** or **185** is preferably equal to or larger than $0.5\text{ mm}\times 15\text{ }\mu\text{m}$ and not larger than $2\text{ mm}\times 60\text{ }\mu\text{m}$. The sidewalls of the contact holes **181**, **182** and **185** are inclined with an angle of about 30-85 degrees or have stepwise profiles.

[0059] A plurality of pixel electrodes **190** and a plurality of contact assistants **81** and **82**, which are preferably made of ITO, IZO or Cr, are formed on the passivation layer **180**.

[0060] The pixel electrodes **190** are physically and electrically connected to the drain electrodes **175** through the contact holes **185** such that the pixel electrodes **190** receive the data voltages from the drain electrodes **175**. The pixel electrodes **190** supplied with the data voltages generate electric fields in cooperation with the common electrode **270**, which reorient liquid crystal molecules disposed therebetween.

[0061] A pixel electrode **190** and a common electrode **270** form a capacitor called a "liquid crystal capacitor," which stores applied voltages after turn-off of the TFT. An additional capacitor called a "storage capacitor," which is connected in parallel to the liquid crystal capacitor, is provided for enhancing the voltage storing capacity. The storage capacitors are implemented by overlapping the pixel electrodes **190** with the storage electrode lines **131**. The capacitances of the storage capacitors, i.e., the storage capacitances can be increased by providing a plurality of storage capacitor conductors, which are electrically connected to the pixel electrodes **190**, between the gate insulating layer **140** and the passivation layer **180** opposite the pixel electrodes **190** and the storage electrode lines **131**.

[0062] The pixel electrodes **190** can overlap the data lines **171** to increase aperture ratio.

[0063] The contact assistants **81** and **82** are connected to the exposed end portions **129** of the gate lines **121** and the exposed end portions **179** of the data lines **171** through the contact holes **181** and **182**, respectively. The contact assistants **81** and **82** protect the exposed portions **129** and **179** and complement the adhesiveness of the exposed portions **129** and **179** and external devices.

[0064] Portions of the passivation layer **180** near the contact assistants **81** and **82** may be completely removed, and such a removal is particularly advantageous for a chip-on-glass type LCD.

[0065] A black matrix **220** for preventing light leakage is formed on an insulating substrate **210**, such as, for example, transparent glass. The black matrix **220** includes a plurality of openings facing the pixel electrodes **190** and having substantially the same shape as the pixel electrodes **190**.

[0066] A plurality of red, green and blue color filters **230** is formed substantially in the openings of the black matrix **220**. An exemplary arrangement of the color filters **230** is a stripe type arrangement in which each color filter **230** is arranged in a separate column.

[0067] A common electrode **270** preferably made of transparent conductive material such as ITO and IZO is formed

on the color filters **230** and the black matrix **220**. The common electrode **270** covers the entire surface of the panel **200**.

[0068] The wider surfaces of the spacers **400** are in contact with the common electrode panel **200** as shown in FIG. 7 or in contact with the TFT array panel **100** as shown in FIG. 6. Although FIGS. 5-7 show the spacers **400** located over the data lines **171**, the spacers **400** can be located over the gate lines **121**, the TFTs, or any other area covered by the black matrix **220**.

[0069] A pair of polarizers (not shown) is provided on outer surfaces of the panels **100** and **200**.

[0070] The LCD may be, for example, a twisted nematic (TN) mode LCD where liquid crystal molecules in the liquid crystal layer **3** having positive dielectric anisotropy are aligned parallel to surfaces of the panels **100** and **200** and the molecular orientations are twisted from the surface of one of the panels **100** and **200** to the surface of the other of the panels **100** and **200** in the absence of an electric field. Alternatively, the LCD may be a vertically aligned (VA) mode LCD, that is, the liquid crystal molecules in the liquid crystal layer **3** with negative dielectric anisotropy are aligned vertical to surfaces of the panels **100** and **200** in the absence of an electric field. Alternatively, the LCD may be an optically compensated bend (OCB) mode LCD, where the liquid crystal molecules have a bend alignment symmetrical with respect to a mid-plane between the panels **100** and **200** in the absence of an electric field.

[0071] A method of manufacturing a panel assembly for an LCD according to an embodiment of the invention is now described in detail with reference to FIGS. 1 and 2 as well as FIGS. 5 and 6.

[0072] Referring to FIGS. 5 and 6, a plurality of gate lines **121**, a plurality of data lines **171**, a plurality of TFTs, a plurality of pixel electrodes **190** and the like are formed on an insulating substrate **110** to form a TFT array panel **100**. An organic insulating material is deposited on the panel **100** and patterned by photolithography to form a plurality of spacers **400** between the pixel areas. A black matrix **220**, a plurality of red, green and blue color filters **230**, a common electrode **270**, and so on are formed on another substrate **210** to form a common electrode panel **200**. The size of the spacers **400** is preferably equal to about 110-130% of the distance between the panels **100** and **200**. The formation of the spacers **400** using photolithography enables uniform arrangement of the spacers **400** such that a thin uniform cell gap can be obtained throughout the panels **100** and **200** and prevents the spacers **400** from being placed on the pixel electrodes **190**, thereby improving display characteristics.

[0073] A sealant **500** is coated on one of the panels **100** and **200** as shown in FIGS. 1 and 2. The sealant **500** has a shape of a closed loop without an injection hole for injecting LC. The sealant **500** may be made of thermosetting material or ultraviolet-hardening material and may contain a plurality of ellipsoidal or spherical spacers for keeping the gap between the panels **100** and **200**. Since the sealant **500** has no injection hole, it is important to exactly control the amount of the LC material. To avoid an excessive amount of the LC or an insufficient amount of the LC, a buffer region without LC material is preferably provided at the sealant **500**. The sealant **500** preferably has an anti-reaction film on its surface, which does not react with the LC layer **3**.

[0074] LC material is coated or dropped using an LC coater on one of the panels **100** and **200** coated with the

sealant **500**. The LC coater may have a dice shape such that it can drop the LC material at the LC device areas **101-104**. The LC may be sprayed on the entire surface of the LC device areas **101-104**. In this case, the LC coater has a shape of a sprayer.

[0075] The panels **100** and **200** are delivered to an assembly device having a vacuum chamber. The area surrounded by the panels **100** and **200** and the sealant **500** is evacuated and the panels **100** and **200** are closely adhered to each other using atmospheric pressure such that the distance between the panels **100** and **200** reaches a desired cell gap. The sealant **500** is completely hardened by illumination with an ultra-violet (UV) ray using a light exposer. In this way, the two panels **100** and **200** are assembled to form a panel assembly **120**. The two panels **100** and **200** are exactly aligned during the step of adhering the panels **100** and **200** and the step of illuminating the sealant **500**.

[0076] The panel assembly **120** is separated into the LC device areas **101-104** using a scribing machine.

[0077] While the present invention has been described in detail with reference to the preferred embodiments, it is to be understood that the invention is not limited to the disclosed embodiments, but, on the contrary, is intended to cover various modifications and equivalent arrangements included within the spirit and scope of the appended claims.

What is claimed is:

1. A panel for a liquid crystal display, comprising:

a substrate; and

at least one spacer formed over the substrate, the at least one spacer having a tapered shape with an inclination angle in the range of about 20-about 70 degrees and a height in the range of about 2.5-about 5.0 microns.

2. The panel of claim 1, further comprising:

at least one gate line;

at least one data line that crosses the at least one gate line;

at least one thin film transistor electrically connected to the at least one gate line and the at least one data line; and

at least one pixel electrode electrically connected to the at least one thin film transistor.

3. The panel of claim 2, wherein the at least one spacer is located directly over the at least one data line.

4. The panel of claim 3, further comprising a passivation layer formed over the at least one data line.

5. The panel of claim 4, wherein the at least one spacer is formed over the passivation layer.

6. The panel of claim 5, wherein the at least one spacer has a contact area with the passivation layer in the range of about 600 to about 1,000 square microns.

7. The panel of claim 1, wherein the at least one spacer has a compression deformation equal to or larger than about 0.40 microns in response to about 5 gf.

8. The panel of claim 1, wherein the at least one spacer comprises a plurality of spacers, and the concentration of the plurality of spacers throughout the panel is about 250 to about 450/cm².

9. The panel of claim 1, further comprising:

at least one color filter; and

a common electrode formed over the at least one color filter.

10. A liquid crystal display, comprising:

a first panel;

a second panel disposed opposite the first panel;

at least one spacer disposed between the first panel and the second panel, the spacer having a tapered shape with an inclination angle in the range of about 20-about 70 degrees and a height in the range of about 2.5-about 5.0 microns.

11. The liquid crystal display of claim 10, further comprising:

a liquid crystal layer disposed between the first panel and the second panel.

12. The liquid crystal display of claim 10, wherein the first panel comprises:

at least one gate line;

at least one data line that crosses the at least one gate line;

at least one thin film transistor electrically connected to the at least one gate line and the at least one data line; and

at least one pixel electrode electrically connected to the at least one thin film transistor.

13. The liquid crystal display of claim 12, wherein the at least one spacer is disposed directly over the at least one data line.

14. The liquid crystal display of claim 13, wherein the first panel further comprises a passivation layer formed over the at least one data line.

15. The liquid crystal display of claim 14, wherein the at least one spacer is formed over the passivation layer.

16. The liquid crystal display of claim 10, wherein the at least one spacer has a compression deformation equal to or larger than about 0.40 microns in response to about 5 gf.

17. The liquid crystal display of claim 10, wherein the at least one spacer comprises a plurality of spacers, and the concentration of the plurality of spacers throughout the liquid crystal panel is about 250 to about 450/cm².

18. The liquid crystal display of claim 12, wherein the second panel comprises:

a substrate;

a black matrix formed over the substrate, the black matrix having at least one opening facing the at least one pixel electrode of the first panel;

at least one color filter formed in the at least one opening of the black matrix; and

a common electrode formed over the at least one color filter.

19. The liquid crystal display of claim 10, wherein the at least one spacer has a first end in contact with the first panel and a second end in contact with the second panel.

20. The liquid crystal display of claim 19, wherein the first end of the at least one spacer has a larger surface area than that of the second end of the at least one spacer.

21. The liquid crystal display of claim 19, wherein the first end of the at least one spacer has a smaller surface area than that of the second end of the at least one spacer.

22. The liquid crystal display of claim 19, wherein the first end and the second end of the at least one spacer has a contact area with a respective panel in the range of about 600 to about 1,000 square microns.

23. A method of forming a liquid crystal display, comprising:

forming a thin film transistor array panel including a plurality of pixel electrodes;

forming a plurality of spacers over the thin film transistor array panel between the plurality of pixel electrodes;

forming a common electrode panel;

coating a sealant over at least one of the thin film transistor array panel and the common electrode panel;

adhering the thin film transistor array panel and the common electrode panel together to form a panel assembly; and

scribing the panel assembly to form a liquid crystal display.

24. The method of claim 23, further comprising:

forming a liquid crystal layer over the at least one of the thin film transistor array panel and the common electrode panel coated with the sealant

25. The method of claim 23, wherein the step of forming the plurality of spacers comprises photolithography.

26. The method of claim 23, wherein the step of forming a thin film transistor array panel comprises forming a plurality of gate lines, a plurality of data lines, a plurality of thin film transistors and a plurality of pixel electrodes over a first substrate.

27. The method of claim 23, wherein the step of forming a common electrode panel comprises forming a black matrix, a plurality of color filters, and a common electrode over a second substrate.

28. The method of claim 23, wherein the plurality of spacers have a tapered shape with an inclination angle in the range of about 20-about 70 degrees and a height in the range of about 2.5-about 5.0 microns.

29. The method of claim 26, wherein each of the plurality of spacers is located directly over a data line.

30. The panel of claim 23, wherein the plurality of spacers have a compression deformation equal to or larger than about 0.40 microns in response to about 5 gf.

31. The method of claim 23, wherein the concentration of the plurality of spacers throughout the liquid crystal display is about 250 to about 450/cm².

32. The method of claim 23, wherein each of the plurality of spacers has a first end in contact with the thin film transistor array panel and a second end in contact with the common electrode panel.

33. The method of claim 32, wherein the first end of each of the plurality of spacers has a larger surface area than that of the second end.

34. The liquid crystal display of claim 32, wherein the first end of each of the plurality of spacers has a smaller surface area than that of the second end.

35. The liquid crystal display of claim 32, wherein the first end and the second end of each of the plurality of spacers has a contact area with a respective panel in the range of about 600 to about 1,000 square microns.

专利名称(译)	用于液晶显示器的面板及其形成方法		
公开(公告)号	US20040141142A1	公开(公告)日	2004-07-22
申请号	US10/714495	申请日	2003-11-14
[标]申请(专利权)人(译)	CHOI WOO 李准YEOB		
申请(专利权)人(译)	CHOI WOO 李准YEOB		
当前申请(专利权)人(译)	CHOI WOO 李准YEOB		
[标]发明人	CHOI WOO LEE JUN YEOB		
发明人	CHOI, WOO LEE, JUN-YEOB		
IPC分类号	G02F1/1333 G02F1/1335 G02F1/1339 G02F1/1343		
CPC分类号	G02F1/13394		
优先权	1020020070705 2002-11-14 KR		
其他公开文献	US7142277		
外部链接	Espacenet USPTO		

摘要(译)

一种用于液晶显示器的面板，包括基板和形成在基板上的至少一个间隔物。所述至少一个间隔件具有锥形形状，其倾斜角在约20-约70度的范围内，高度在约2.5-约5.0微米的范围内。

